

POWEREX

M54564P/FP

8-UNIT 500mA SOURCE TYPE DARLINGTON TRANSISTOR ARRAY

DESCRIPTION

M54564P and M54564FP are eight-circuit output-sourcing Darlington transistor arrays. The circuits are made of PNP and NPN transistors. Both the semiconductor integrated circuits perform high-current driving with extremely low input-current supply.

FEATURES

- High breakdown voltage ($BV_{CEO} \geq 50V$)
- High-current driving ($I_{O(max)} = -500mA$)
- With output pulldown resistance (Driving available with fluorescent display tube)
- Driving available with PMOS IC output or with TTL output
- Wide operating temperature range ($T_a = -20$ to $+75^\circ C$)
- Output current-sourcing type

APPLICATION

Drives of relays, printers, LEDs, fluorescent display tubes and lamps, and interfaces between MOS-bipolar logic systems and relays, solenoids, or small motors

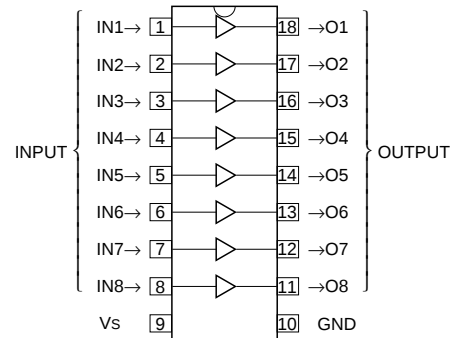
FUNCTION

The M54564P and M54564FP each have eight circuits, which are made of input inverters and current-sourcing outputs. The outputs are made of PNP transistors and NPN Darlington transistors. The PNP transistor base current is constant. Resistance of $50k\Omega$ is connected between each output pin and GND, making these ICs suitable for fluorescent display tubes. V_s and GND are used commonly among the eight circuits.

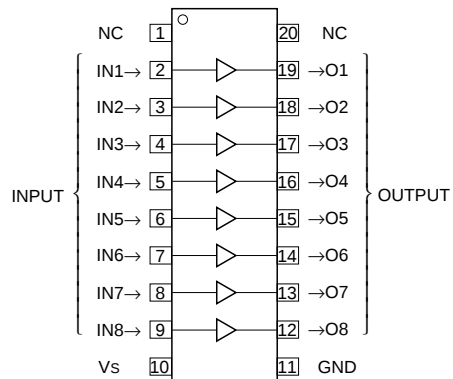
Output current is 500mA maximum. Supply voltage V_s is 50V maximum.

The M54564FP is enclosed in a molded small flat package, enabling space-saving design.

PIN CONFIGURATION



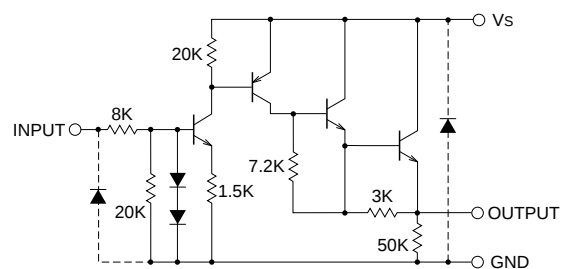
Package type 18P4G(P)



Package type 20P2N-A(FP)

NC : No connection

CIRCUIT DIAGRAM



The eight circuits share the V_s and GND.

The diode, indicated with the dotted line, is parasitic, and cannot be used.

Unit : Ω

POWEX

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ABSOLUTE MAXIMUM RATINGS (Unless otherwise noted, Ta = -20 ~ +75°C)

Symbol	Parameter	Conditions	Ratings	Unit
V _{CEO}	Collector-emitter voltage	Output, L	-0.5 ~ +50	V
V _S	Supply voltage		50	V
V _I	Input voltage		-0.5 ~ +30	V
I _O	Output current	Current per circuit output, H	-500	mA
P _d	Power dissipation	Ta = 25°C, when mounted on board	1.79(P)/1.10(FP)	W
T _{opr}	Operating temperature		-20 ~ +75	°C
T _{stg}	Storage temperature		-55 ~ +125	°C

RECOMMENDED OPERATING CONDITIONS (Unless otherwise noted, Ta = -20 ~ +75°C)

Symbol	Parameter	Limits			Unit
		min	typ	max	
V _S	Supply voltage	0	—	50	V
I _O	Output current (Current per 1 circuit when 8 circuits are coming on simultaneously)	0	—	-350	mA
	Duty Cycle P : no more than 8% FP : no more than 5%	0	—	-100	
V _{IH}	"H" input voltage	2.4	—	25	V
V _{IL}	"L" input voltage	0	—	0.2	V

ELECTRICAL CHARACTERISTICS (Unless otherwise noted, Ta = -20 ~ +75°C)

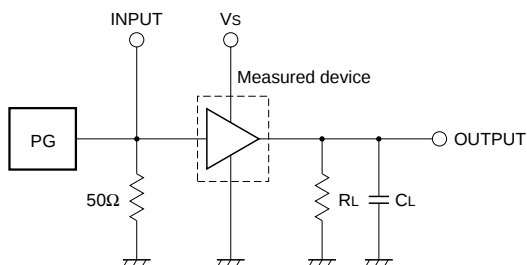
Symbol	Parameter	Test conditions	Limits			Unit
			min	typ*	max	
I _S (leak)	Supply leak current	V _S = 50V, V _I = 0.2V	—	—	100	μA
V _{CE} (sat)	Collector-emitter saturation voltage	V _S = 10V, V _I = 2.4V, I _O = -350mA	—	1.6	2.4	V
		V _S = 10V, V _I = 2.4V, I _O = -100mA	—	1.45	2.0	
I _I	Input current	V _I = 5V, V _S = 10V	—	0.4	0.7	mA
		V _I = 25V, V _S = 30V	—	2.9	6.5	
I _S	Supply current	V _S = 50V, V _I = 5V	—	—	5.0	mA

* : The typical values are those measured under ambient temperature (Ta) of 25°C. There is no guarantee that these values are obtained under any conditions.

SWITCHING CHARACTERISTICS (Unless otherwise noted, Ta = 25°C)

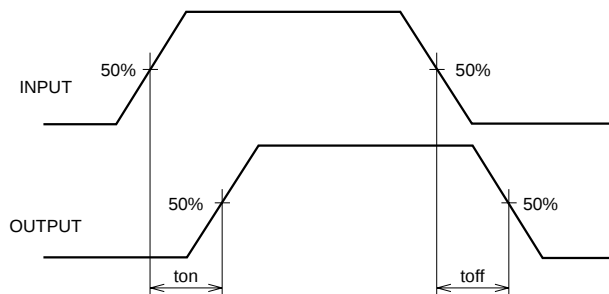
Symbol	Parameter	Test conditions	Limits			Unit
			min	typ	max	
t _{on}	Turn-on time	C _L = 15pF (note 1)	—	185	—	ns
t _{off}	Turn-off time		—	4300	—	ns

NOTE 1 TEST CIRCUIT



- (1) Pulse generator (PG) characteristics : PRR = 1kHz,
 $t_w = 10\mu s$, $t_r = 6ns$, $t_f = 6ns$, $Z_o = 50\Omega$
 $V_i = 0$ to $2.4V$
- (2) Input-output conditions : $R_L = 30\Omega$, $V_s = 10V$
- (3) Electrostatic capacity C_L includes floating capacitance at connections and input capacitance at probes

TIMING DIAGRAM



TYPICAL CHARACTERISTICS

